

**WP27-JRA9**  
**Tracking and Ions Identifications with Minimal Material budget**  
**( TIIMM )**

*This project has received funding from the European Union's Horizon 2020 research and innovation programme under grant JRA9 TIIMM presentatio*

*agreement No 824093*



# Talk overview

1. Remind of the workpage goals

verified cluster size dependence from charge released in MAPS

fully depletion could improve charge measure resolution

2. Accomplished activities (main achievements)

TIIMM0 construction and test

3. Activities underway

4. Deliverables and milestones status

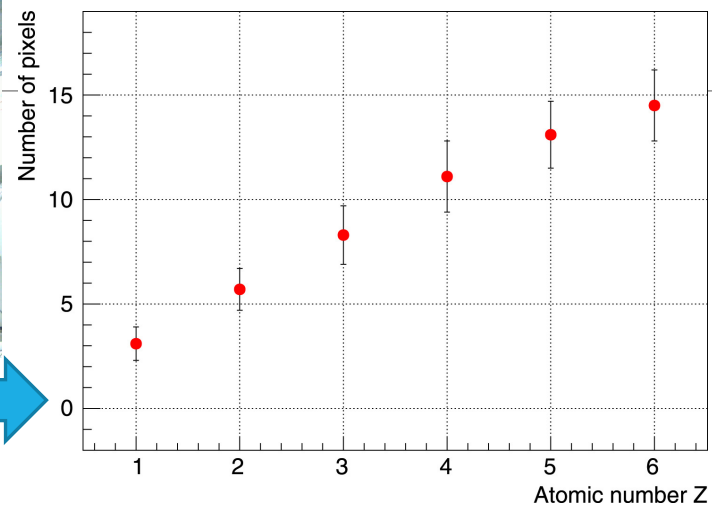
5. Summary: difficulties, delays, future planning

# Remind of the workpage goals



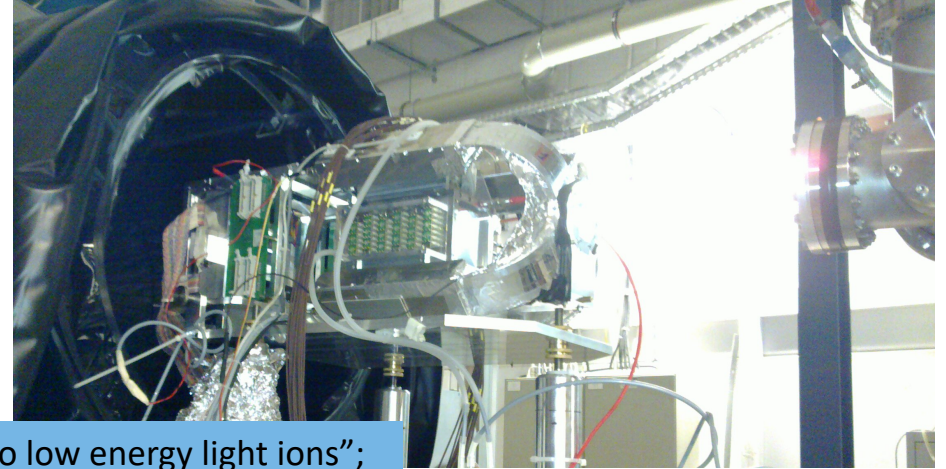
Number of pixel per cluster vs ion atomic number in FIRST data taking at GSI. Measured in the MAPS (M26) vertex detector.

## dE/dx in existing MAPS: where do we stand.

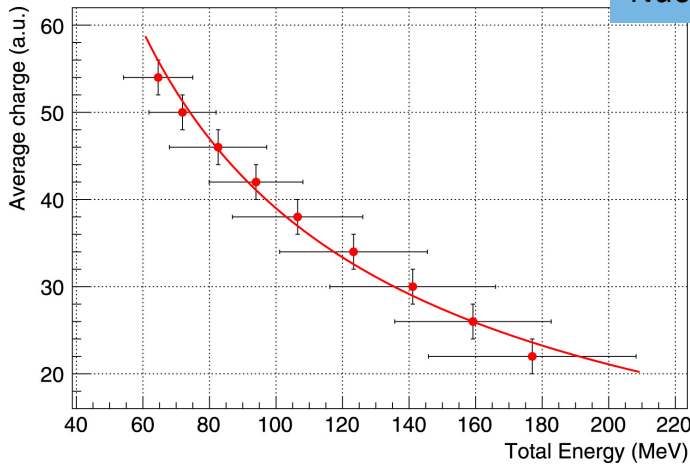


## FIRST (Fragmentation of Ions for R Space and Therapy)

M. Toppi et al., "Measurement of fragmentation cross sections of C ions on a thin gold target with the FIRST apparatus," Phys. Rev. C, vol. 93, no. 6, p. 064601, 2016.



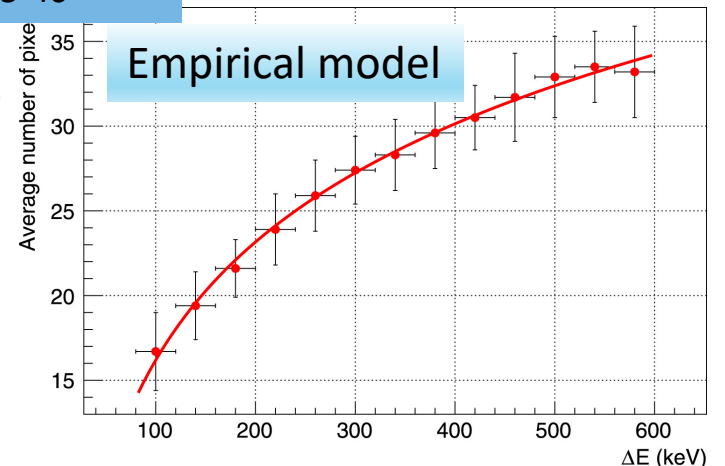
E. Spirti et al., "CMOS active pixel sensors response to low energy light ions"; Nuclear Inst. and Methods in Physics Research. A 875C (2017) pp. 35-40



$$n_p = \frac{\pi r_T^2}{p^2} = 2\pi r_s \text{Log}\left(\frac{\Delta E}{2\pi E_g T_s}\right)$$

$r_s = \sigma^2/p^2$  and  $T_s = T\sigma^2$  (only two parameters)  
 $\sigma$  = spread of Gaussian charge diffusion, T = single pixel charge threshold

Measured (M18 sensor) released charge in 14 μm thick silicon epitaxial layer vs total ion (Z=2) energy (measured in CsI telescope).

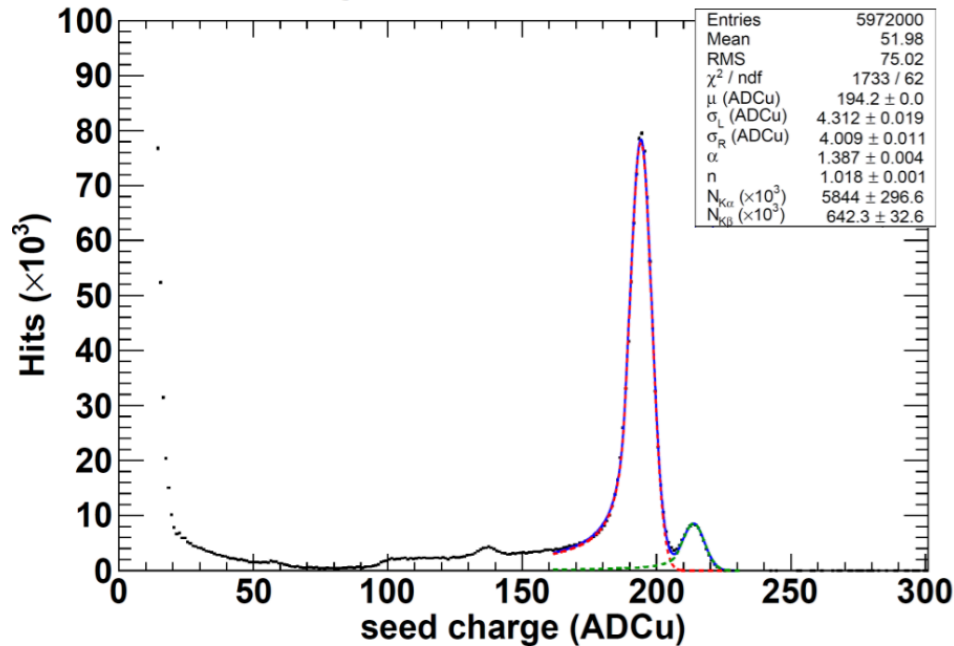


## Empirical model

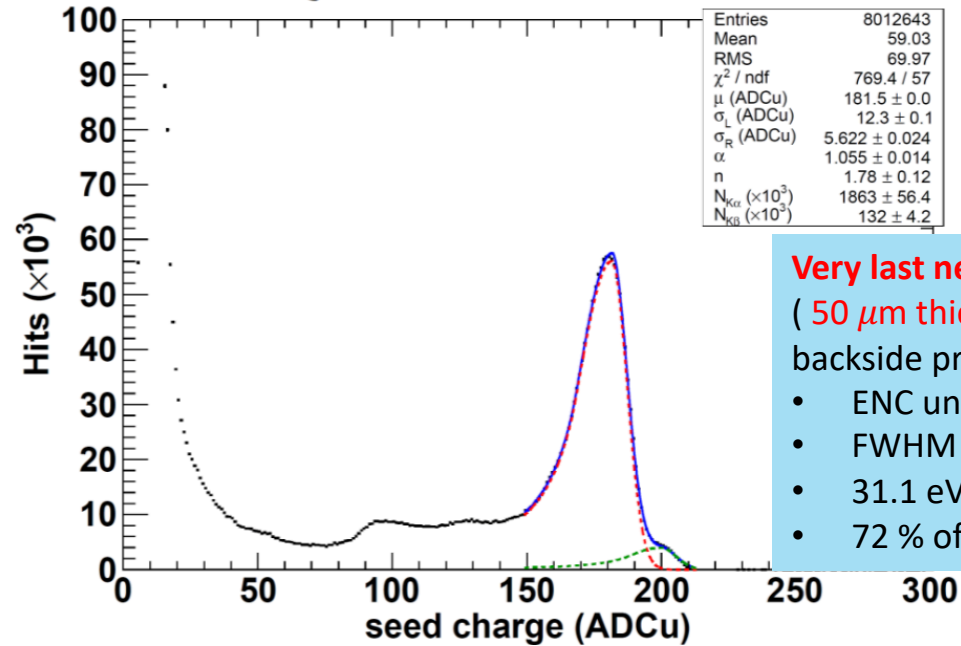
# Remind of the workpage goals

## After clustering → Seed pixel charge distribution

- **18 μm thick epitaxial layer (HR18)**
  - ❑ ENC = 24 e<sup>-</sup>
  - ❑ FWHM (5.9 keV) = 298 eV
  - ❑ 30.38 eV/ADCu
  - ❑ Si escape peak visible (138 ADCu)
  - ❑ 75 % of the charges collected on the seed pixel on average



- **280 μm thick Czochralski (CZ)**
  - ❑ ENC = 26 e<sup>-</sup>
  - ❑ FWHM (5.9 keV) = 686 eV
  - ❑ 32.51 eV/ADCu
  - ❑ Mn-K $\alpha$  and Mn-K $\beta$  merging
  - ❑ 68 % of the charges collected on the seed pixel on average



J. Heymes ; “Performances of depleted Monolithic Active Pixel Sensor in a high-resistivity CMOS process for X-ray detection”, slide, 11th International Conference on Position Sensitive Detectors PSD2017, Milton Keynes, the UK, 3-8 September 2017

**Very last news (preliminar)!**  
 ( 50 μm thick, CZ silicon, backside processed, 30V bias )

- ENC unchanged
- FWHM = = 350 eV
- 31.1 eV/ADCu
- 72 % of charge on seed pixel

Pipper-2 measurements (presc. 2, T<sup>o</sup><sub>cool</sub>=7 °C, V<sub>diode</sub>=30V) <sup>55</sup>Fe irradiation – 400000 frames

# Remind of the workpage goals

Precision Tracking  
( few  $\mu\text{m}$  obtained)



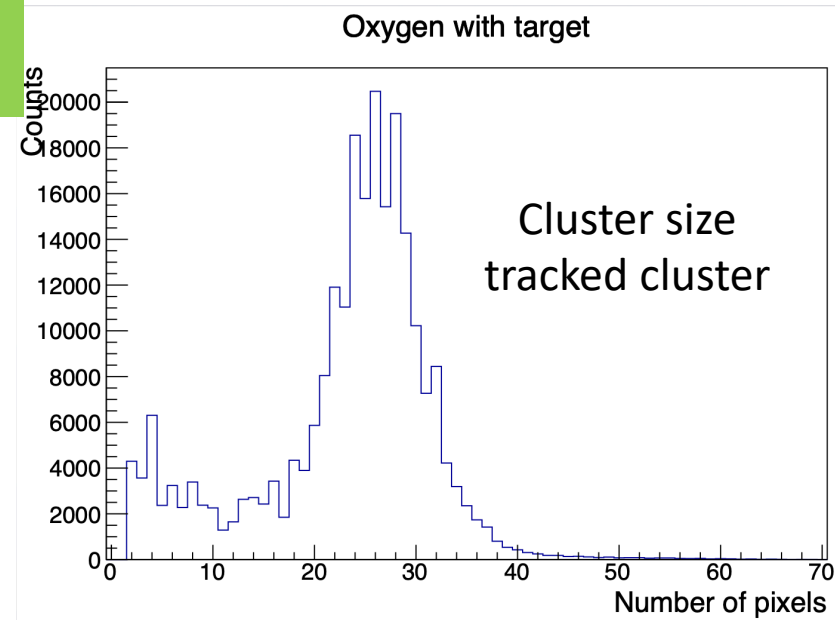
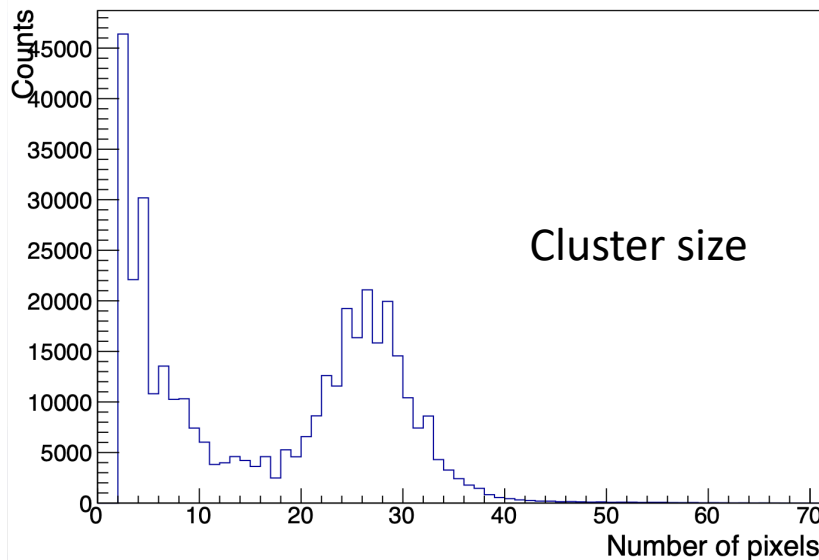
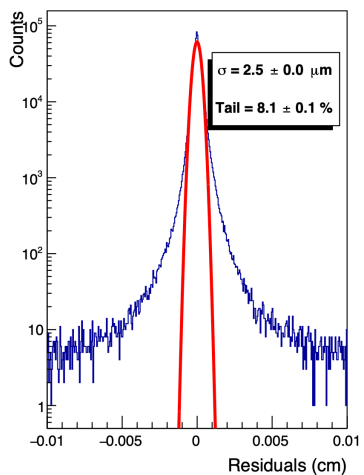
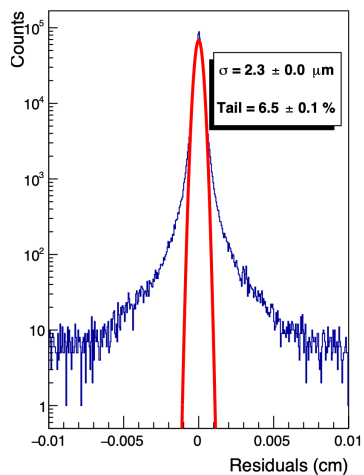
Low material Budget  
( 0.3 %  $X_0$  achieved )



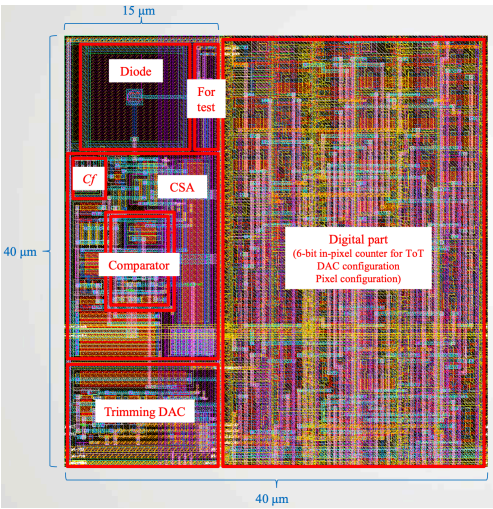
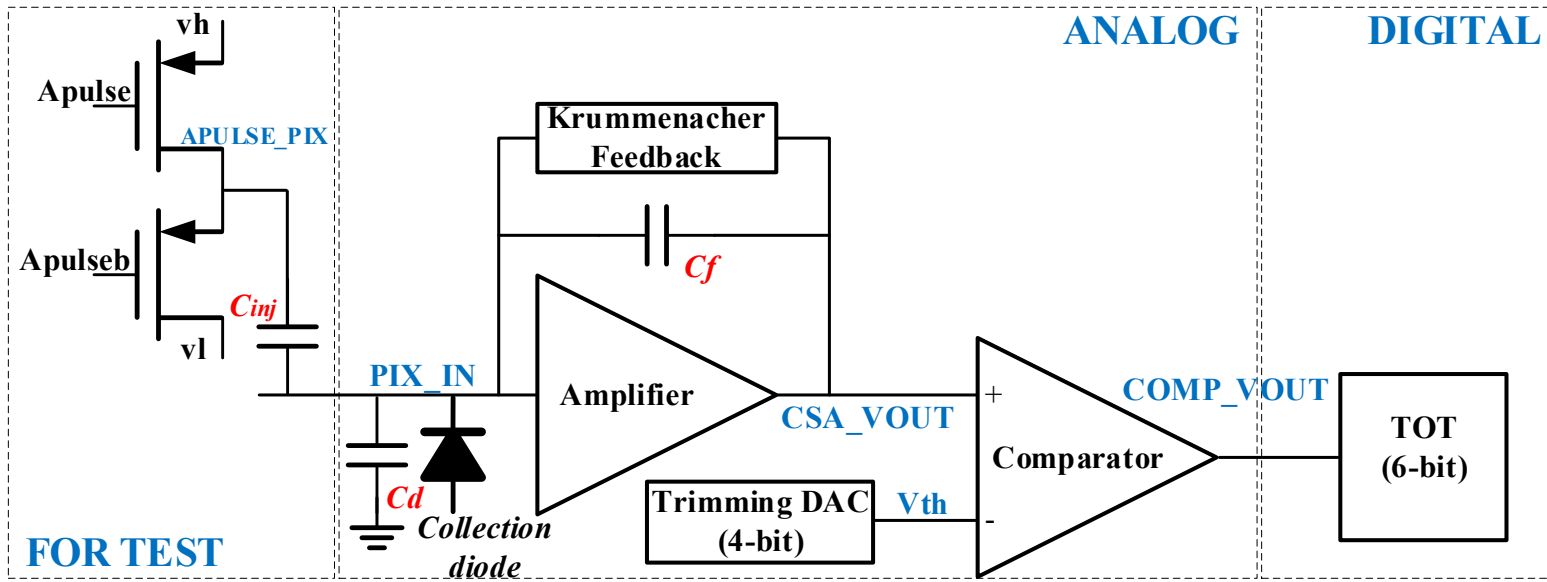
Energy loss measurement  
( still **missing** on large area )

VTX alignment residuals  
(cluster size > 20):

FOOT-Vertex data with Oxygen beam @GSI July 2021  
(Courtesy C.Finck, FOOT collaboration)

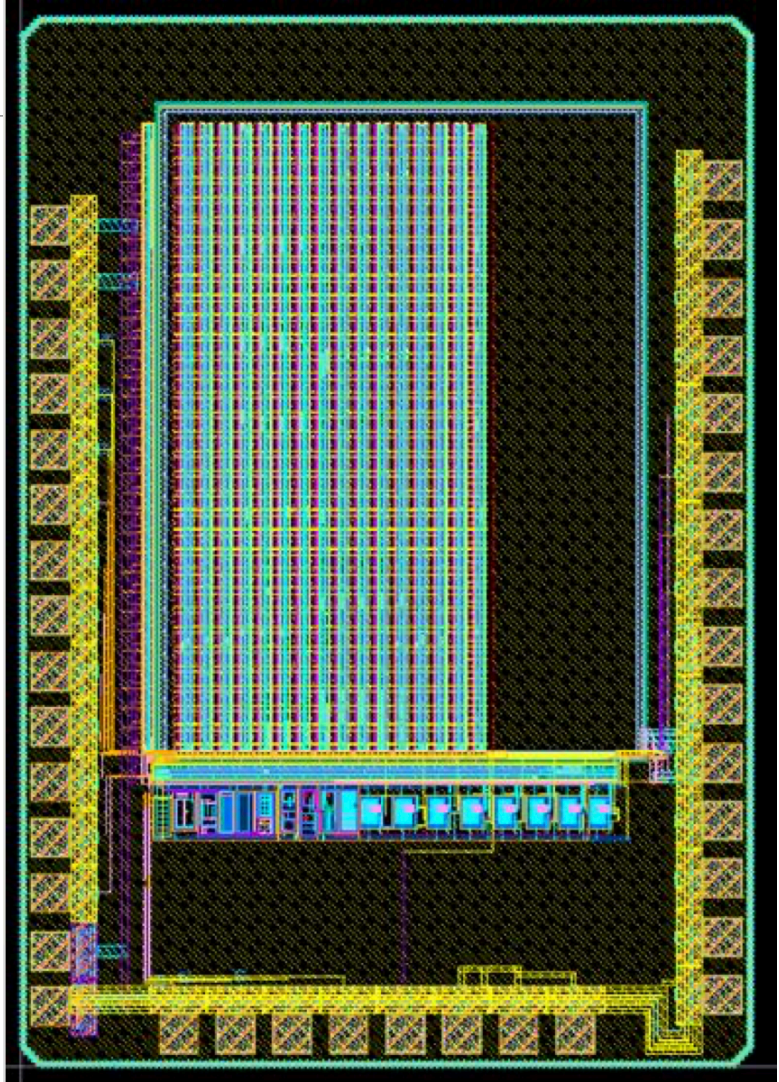


# Accomplished activities - TIIMM-0 prototype

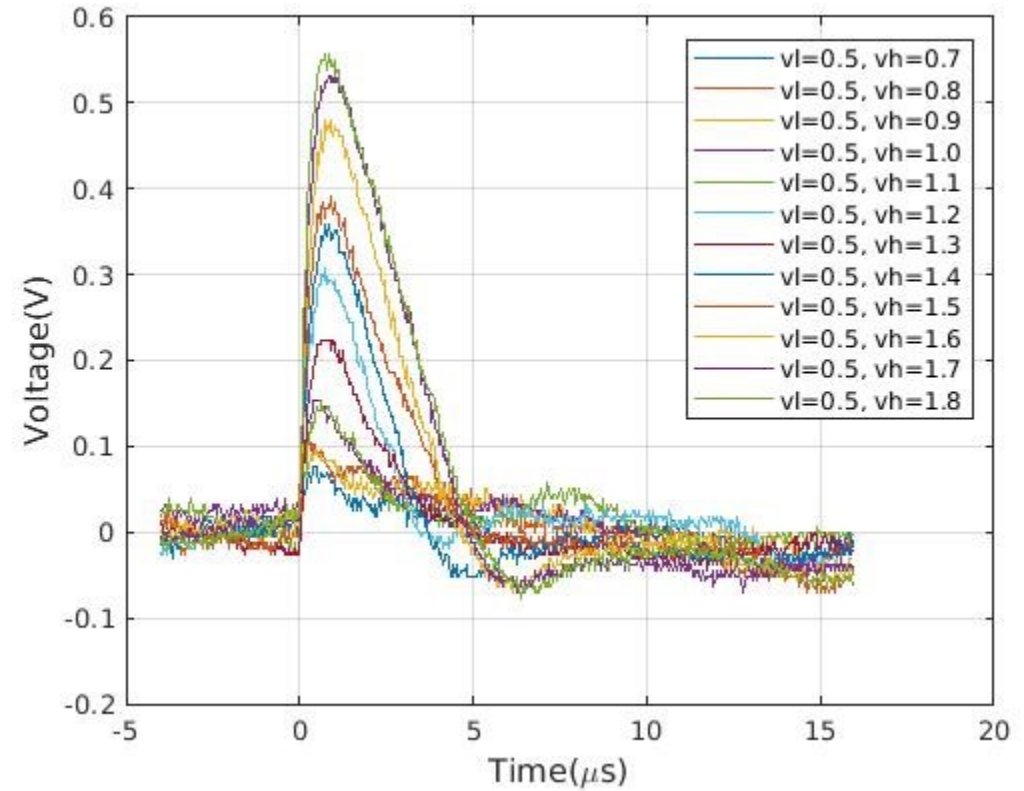
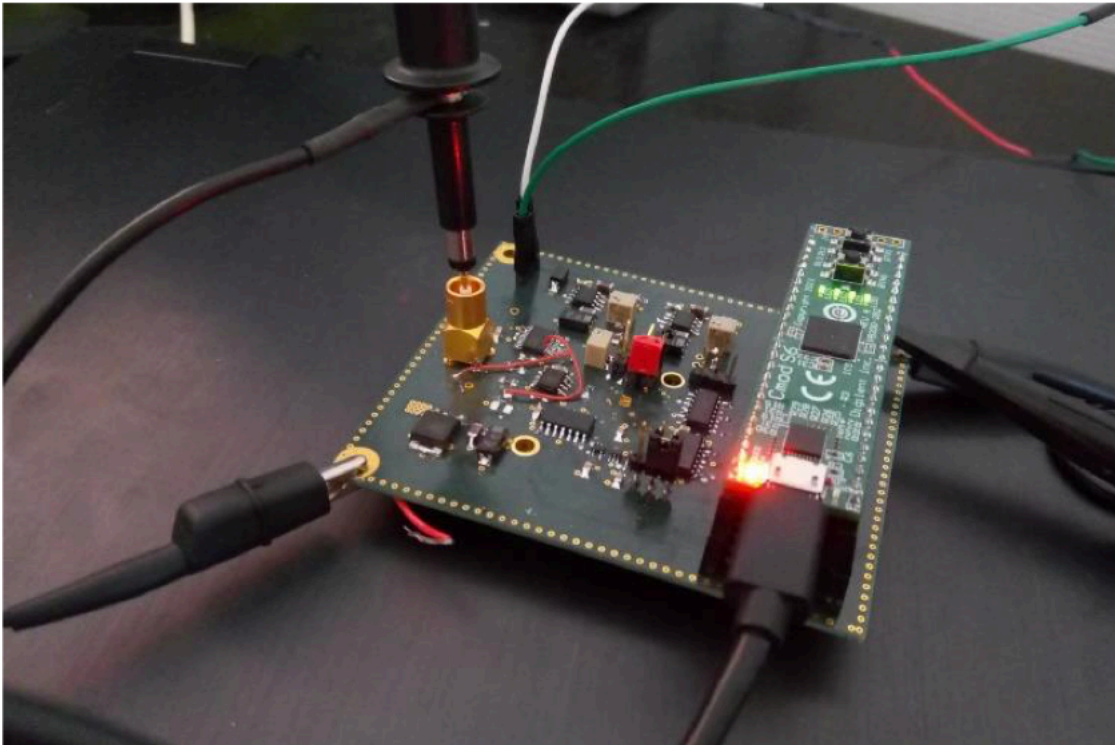


**TIIMM-0**

- Pixel pitch: 40μm
- C<sub>f</sub>: 1fF
- TOT (6 bits)
- Trimming DAC (4 bits)
- ENC: 42 e<sup>-</sup>
- Matrix: 32 rows x 16 columns  
+1 column with analogue out
- Chip area: 2.2 mm \* 1.5 mm
- Position and energy measurements



# Accomplished activities - TIIMM-0 prototype



Analogue output of the CSA with different input charge

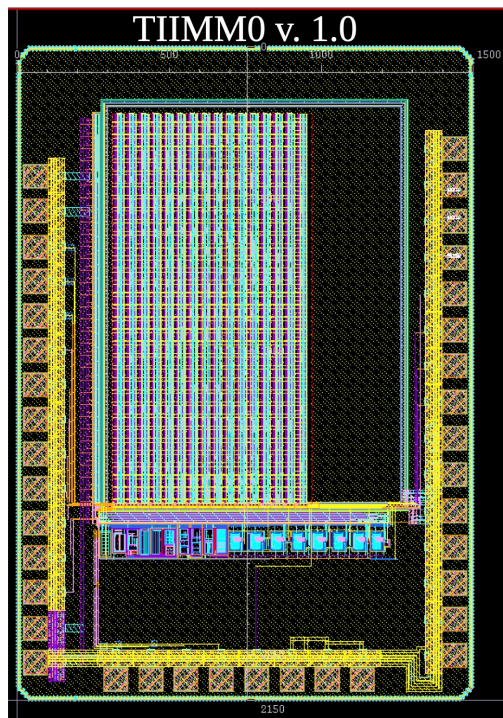
## SETUP

- CMODS6 Digilent module (FPGA)
- Tektronix TDS5054 scope
- Keithley 237 current source

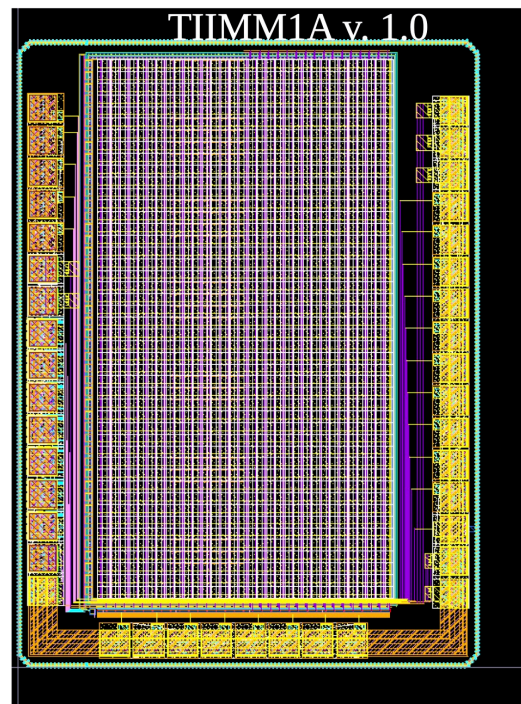
Some bugs in the pulsing circuitry and in the on-chip DAC settings circuitry prevented any reasonable test on beam.  
**Waiting for TIIMM1 prototypes to make further tests.**

# Activities underway: TIIMM-1 prototype

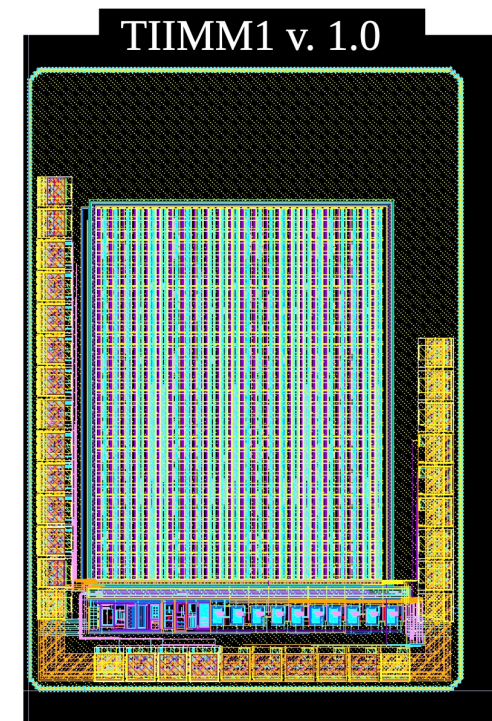
Starting from the TIIMM-0 experience we designed three versions of the new sensors to be tested separately. Submission to silicon foundry those days in **3 different epitaxial layer thickness 25 $\mu$ m 50 $\mu$ m and 100 $\mu$ m.**



Corrected version of TIIMM0



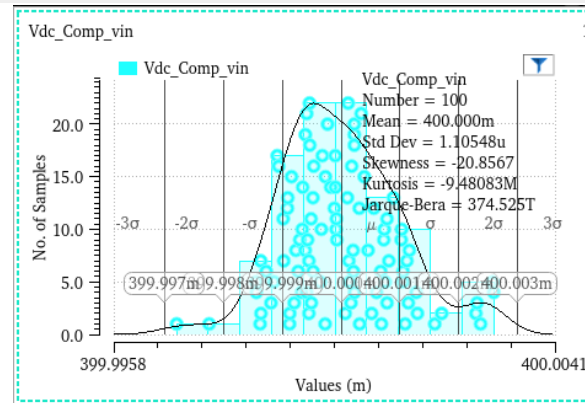
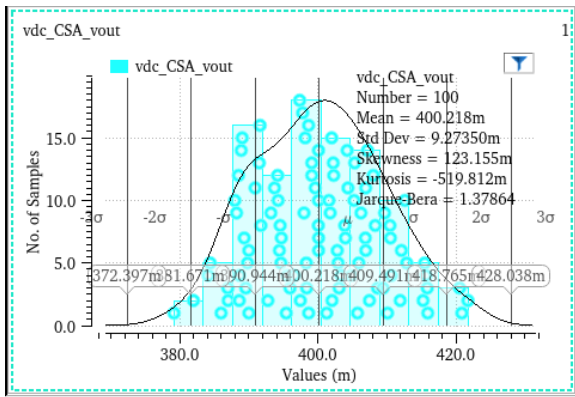
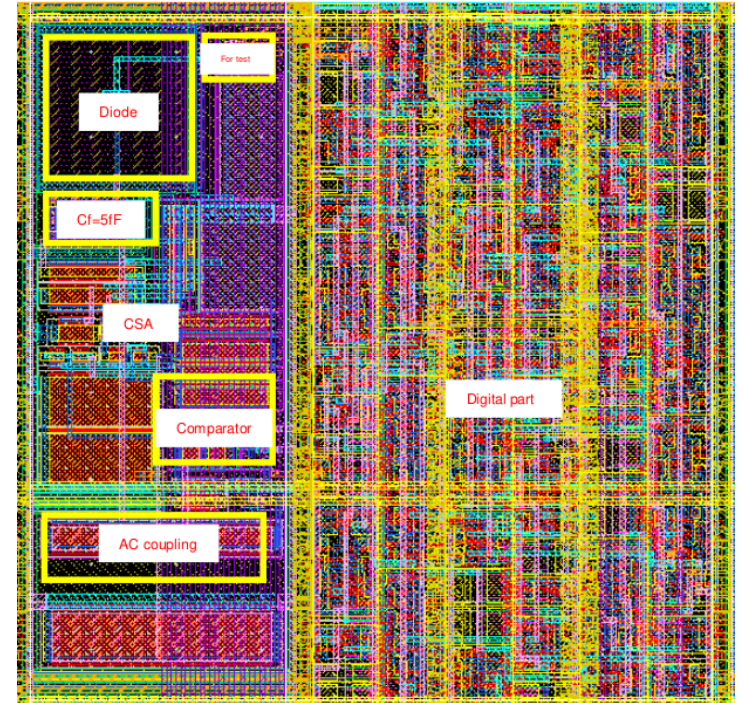
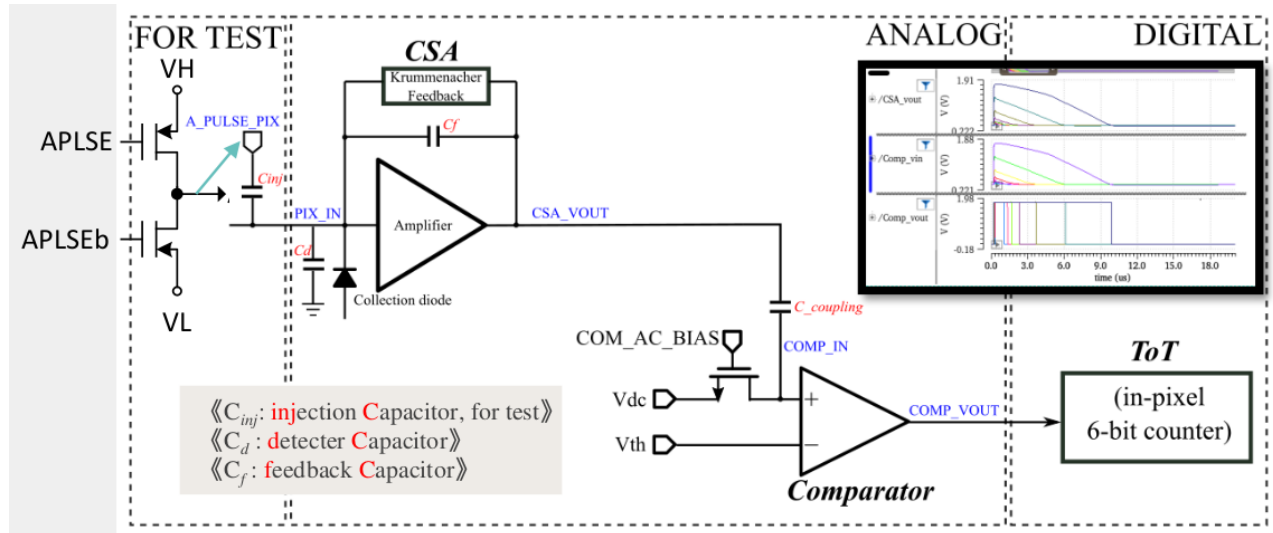
TIIMM1A pixel analog front-end only  
( see presentation by W.Ren at  
PSD2021 )



TIIMM1 full version with new  
analog front-end enlarging the  
dynamic range



# Activities underway: TIIMM-1 prototype

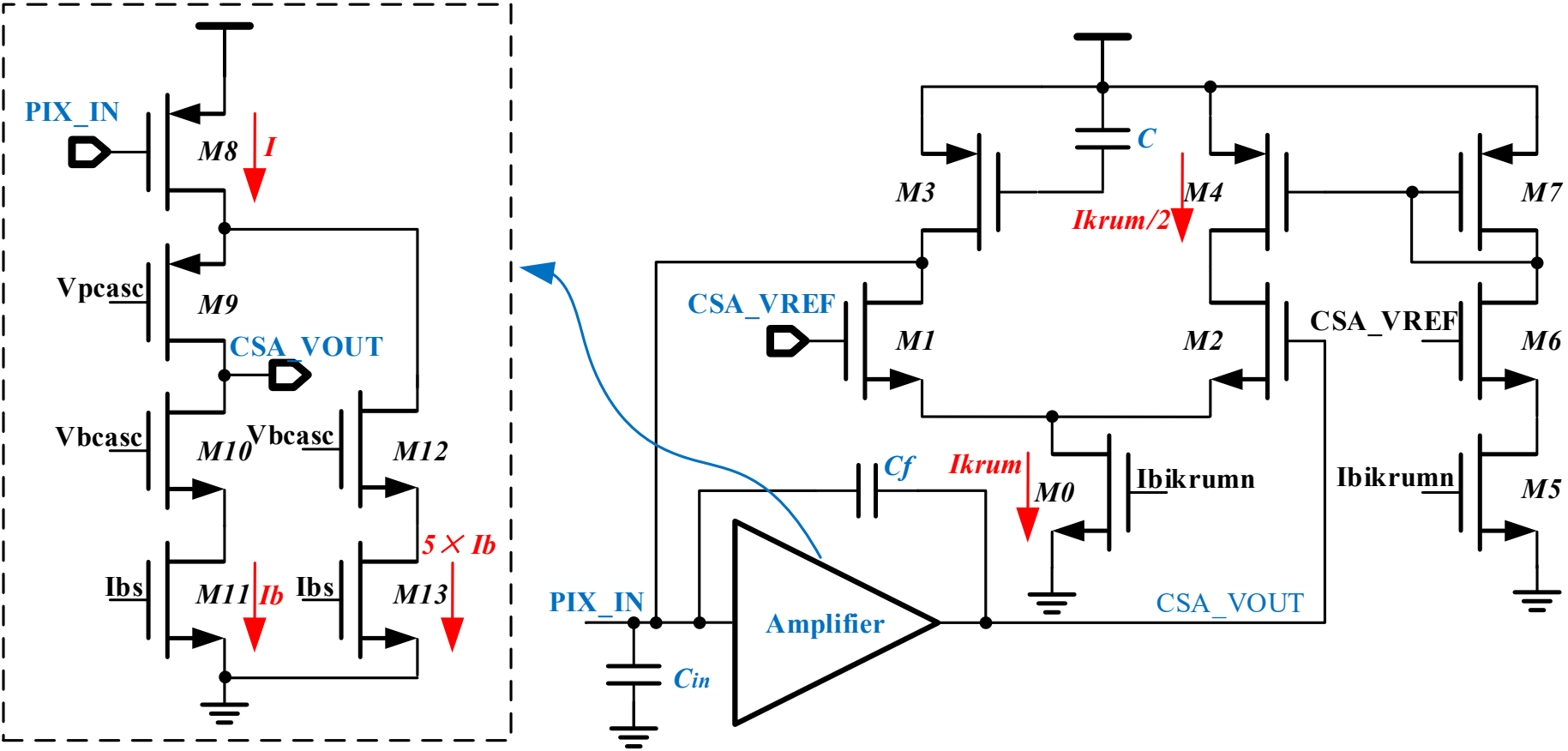


Offset spread of the CSA  
 Mean: 400.22 mV  
 Sigma: 9.27 mV  
 sigma/mean: 2.32%

Offset spread after AC coupling  
 Mean: 400 mV  
 Sigma: 1.11  $\mu$ V  
 sigma/mean: 0.00026%

# Activities underway: TIIMM-1 prototype

Schematic of CSA with the Krummenacher Feedback circuit



# Activities underway: TIIMM-1 prototype

Dynamic range comparison (simulation) between TIIMM0 and TIIMM1 analog front-end

TIIMM-0, Pulse width of signals from Monte Carlo Simulation,									
csa_vout	Qin/ke <sup>-</sup>	0.5	1	2	5	10	50	100	200
	Mean/ns	395.8	490.1	751	1434	2208	6274	9810	4083
	Sigma/ns	85.03	115.4	228.2	474	749.1	2023	2882	840.8
	Sigma/Mean	21.48%	23.55%	30.39%	33.05%	33.93%	32.24%	29.38%	20.59%

TIIMM-1, Pulse width of signals from Monte Carlo Simulation,									
csa_vout	Qin/ke <sup>-</sup>	0.5	1	2	5	10	50	100	200
	Mean/ns	282.8	596.6	924.4	1957	3818	14290	23820	37100
	Sigma/ns	18.72	30.73	67.47	178.6	358.8	1379	2304	3559
	Sigma/Mean	6.62%	5.15%	7.30%	9.13%	9.40%	9.65%	9.67%	9.59%

Pulse width spread vs Qin(500e<sup>-</sup>~200ke<sup>-</sup>)

For the pulse width of signal csa\_vout, the mean value and the sigma value increases with the Qin from 1ke<sup>-</sup>, and the value of sigma/mean seems to saturate 10% in TIIMM-1 after optimization.

# Deliverables and milestones status

## 3.1.2 TIMING OF THE DIFFERENT WORK PACKAGES AND THEIR COMPONENTS

Work package number	JRAX															
Work package acronym	TIIMM															
Work package title	Tracking and Ions Identifications with Minimal Material budget															
TASKS/Subtasks	Year 1				Year 2				Year 3				Year 4			
	Q1	Q2	Q3	Q4	Q1	Q2	Q3	Q4	Q1	Q2	Q3	Q4	Q1	Q2	Q3	Q4
<b>Task 1 Sensors and final device requirements definition</b>																
1.1 Sensors and final device requirements definition																
<b>Task 2 Sensors design</b>																
2.1 Design of the first sensor prototype																
2.2 Design of the second sensor prototype																
<b>Task 3 Production of the sensors</b>																
3.1 Production of the first sensor prototype																
3.2 Production of the second sensor prototype																
<b>Task 4 Preparation of the test set-up</b>																
4.1 Preparation of the first sensor test set up																
4.2 Preparation of the final device test set up																
<b>Task 5 Testing and reporting of results</b>																
5.1 Testing of the first prototype																
5.2 Report on the first prototype obtained performances																
5.3 Testing of the second prototype (multisensor device)																
5.4 Simulation and modelling of the performances																
5.5 Report on the possibilities for PID from the results																

(Timelines are indicate in grey, milestones with black boxes)

June 2019      June 2020      June 2021      today      June 2022

MS60

Deliverable D27.2 - MS62

Deliverable D27.1 - MS61

# Summary: difficulties, delays, future planning

- **Task 3.1:** Production of the first sensor prototype accomplished in time
- **Task 5.1:** Testing of the first prototype accomplished in time (**results not fully satisfactory**)
- **Task 3.2:** TIIMM1 sensors production
  - Design of the three versions ( TIIMM0new, TIIMM1-A, TIIMM1 ) ready
  - Submission to Silicon foundry those days ( novembre 2021 )
  - Turn around longer due to semiconductor crisis (6 instead 4 months )
  - Cost of the submission increased due to semiconductor crisis
- **Task 4.2:** Preparation of the final test setup started october 2021 (**supposed ready Q3 2021**)
  - Sensors testing PCB board design started ( production start january 2022 )
  - Readout board based on Terasic ADC-SoC-P0435 board ( available ) – firmware under development
- **Task 5.2:** Testing of the second prototype ( **start planned for june 2022, supposed Q4 2021** )
- One talk given at **PSD 2021** and one submitted at **VCI 2022**

**A 6 months prolongation of the overall project would be highly desirable**